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Kind regards,

Team Nexperia



45 V/60 V/80 V, 1 A PNP medium power transistors
Rev. 1 — 19 June 2015 Produ

Product data sheet

Product profile

1.1 General description

PNP medium power transistor series encapsulated in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and visible and solderable side pads.

Table 1. Product overview

Type number[1]	Package		NPN complement
BC51PAS	DFN2020D-3	SOT1061D	BC54PAS
BC52PAS			BC55PAS
BC53PAS			BC56PAS

[1] Valid for all available selection groups.

1.2 Features and benefits

- High collector current capability I_C and I_{CM}
- Reduced Printed-Circuit Board (PCB) area requirements
- Exposed heat sink for excellent thermal and electrical conductivity
- AEC-Q101 qualified

- Three current gain selections
- Leadless very small SMD plastic package with medium power capability
- Suitable for Automatic Optical Inspection (AOI) of solder joint

- 1.3 Applications
 - Linear voltage regulators
 - Battery driven devices
 - MOSFET drivers

- High-side switches
- Power management
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

T_{amb} = 25 °C unless otherwise specified

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base				
	BC51PAS series		-	-	-45	V
	BC52PAS series		-	-	-60	V
	BC53PAS series		-	-	-80	V



45 V/60 V/80 V, 1 A PNP medium power transistors

Table 2. Quick reference data ...continued

 T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Ic	collector current			-	-	-1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	-2	Α
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V; } I_{C} = -150 \text{ mA}$	11	63	-	250	
	h _{FE} selection -10	$V_{CE} = -2 \text{ V; } I_{C} = -150 \text{ mA}$	[1]	63	-	160	
	h _{FE} selection -16	$V_{CE} = -2 \text{ V; } I_{C} = -150 \text{ mA}$	[1]	100	-	250	

^[1] Pulse test: $t_p \le 300 \text{ ms}$; $\delta \le 0.02$.

2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	base		_
2	emitter	3	3
3	collector	Transparent top view	1

3. Ordering information

Table 4. Ordering information

Type number[1]	Package	Package		
	Name	Description	Version	
BC51PAS series	DFN2020D-3	plastic thermal enhanced ultra thin small	SOT1061D	
BC52PAS series		outline package; no leads; 3 terminals;		
BC53PAS series		body $2 \times 2 \times 0.65$ mm.		

^[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes

Type number	Marking code
BC51PAS	C4
BC51-10PAS	C5
BC51-16PAS	C6
BC52PAS	C7
BC52-10PAS	C8
BC52-16PAS	C9
BC53PAS	CA
BC53-10PAS	СВ
BC53-16PAS	CC

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

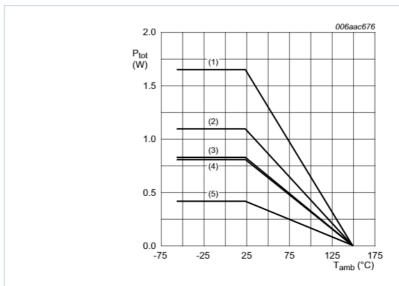
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter			
	BC51PAS series		-	-45	V
	BC52PAS series		-	-60	V
	BC53PAS series		-	-100	V
V _{CEO}	collector-emitter voltage	open base			
	BC51PAS series		-	-45	V
	BC52PAS series		-	-60	V
	BC53PAS series		-	-80	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current		-	-1	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-2	Α
I _B	base current		-	-0.3	Α

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$ [1]	-	0.42	W
		[2]	-	0.81	W
		[3]	-	0.83	W
		[4]	-	1.10	W
		[5]	-	1.65	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C
T _{stg}	storage temperature		-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm².



- (1) FR4 PCB, 4-layer copper, 1 cm²
- (2) FR4 PCB, single-sided copper, 6 cm2
- (3) FR4 PCB, single-sided copper, 1 cm2
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 1. Power derating curves

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air 11	298	K/W
		[2]	154	K/W
			151	K/W
			114	K/W
		[5]	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point	in free air	20	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm²

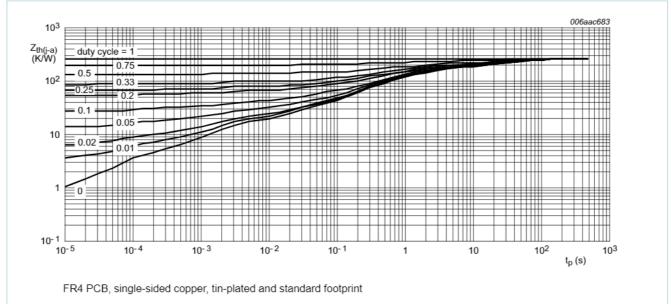


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

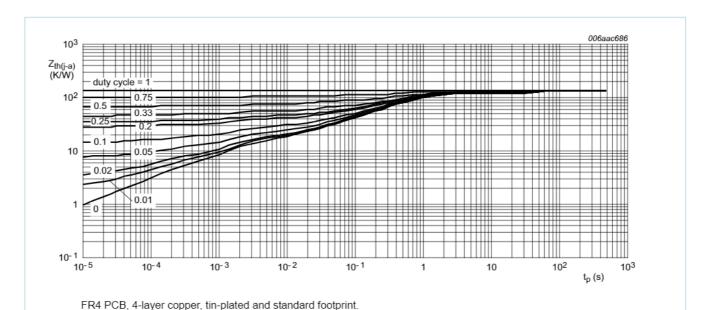
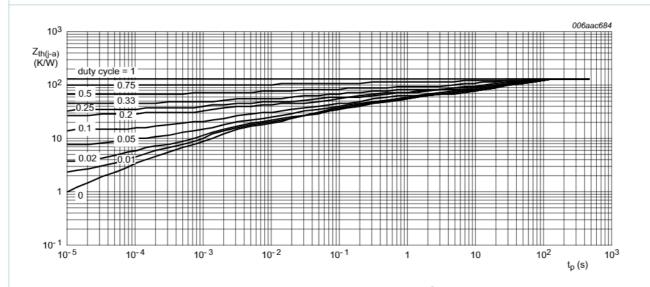


Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm²

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

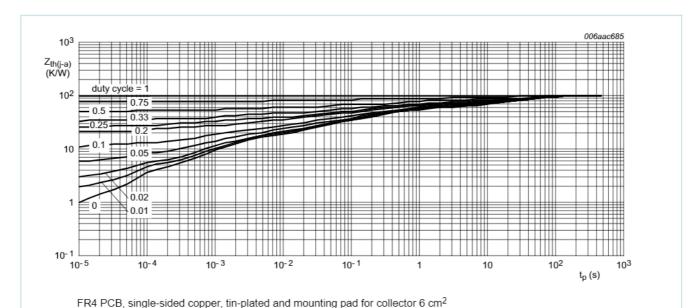
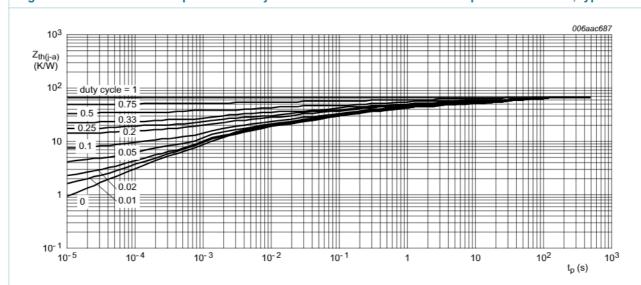


Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm²

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

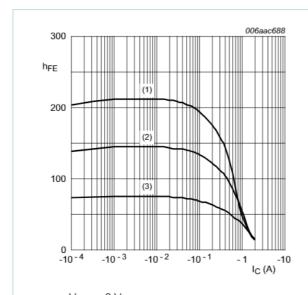
7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_{E} = 0 \text{ A}$		-	-	-100	nΑ
		$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	-10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	-100	nΑ
h _{FE} DC current gain	$V_{CE} = -2 \text{ V; } I_{C} = -5 \text{ mA}$		63	-	-		
		$V_{CE} = -2 \text{ V; } I_{C} = -150 \text{ mA}$	[1]	63	-	250	
		$V_{CE} = -2 \text{ V; } I_{C} = -500 \text{ mA}$	[1]	40	-	-	
	h _{FE} selection -10	$V_{CE} = -2 \text{ V; } I_{C} = -150 \text{ mA}$	[1]	63	-	160	
	h _{FE} selection -16	$V_{CE} = -2 \text{ V; } I_{C} = -150 \text{ mA}$	[1]	100	-	250	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	[1]	-	-	-500	mV
V _{BE}	base-emitter voltage	$V_{CE} = -2 \text{ V; } I_{C} = -500 \text{ mA}$	[1]	-	-	-1	V
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	15	-	pF
f⊤	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -50 \text{ mA}; f = 100 \text{ MHz}$		-	145	-	MHz

[1] Pulse test: $t_p \le 300$ ms; $\delta \le 0.02$.





- (1) T_{amb} = 100 °C
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \,^{\circ}C$

Fig 7. DC current gain as a function of collector current; typical values

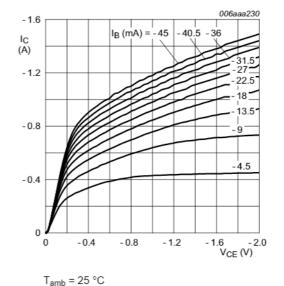
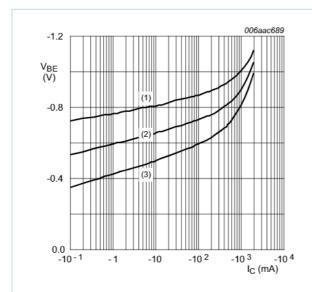
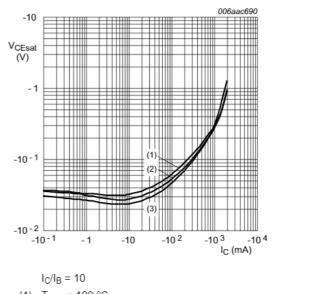


Fig 8. Collector current as a function of collector-emitter voltage; typical values



- $V_{CE} = -2 V$
- (1) $T_{amb} = -55 \,^{\circ}C$
- (2) T_{amb} = 25 °C
- (3) T_{amb} = 100 °C

Fig 9. Base-emitter voltage as a function of collector current; typical values



- (1) T_{amb} = 100 °C
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \,^{\circ}C$

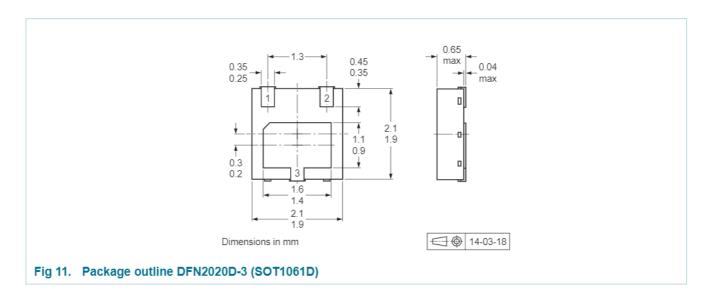
Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values

8. Test information

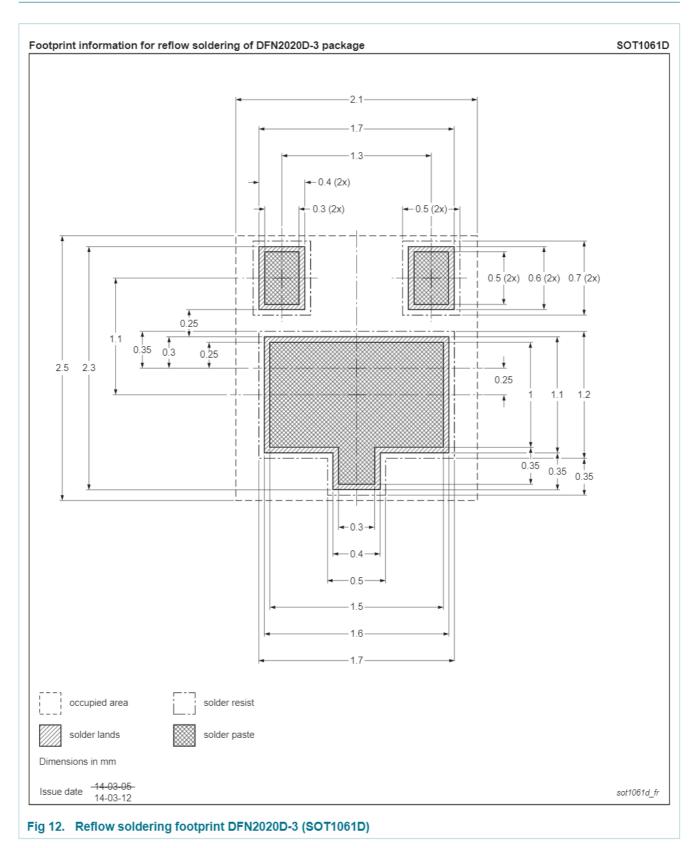
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Soldering



11. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC51_52_53PAS_SER v.1	20150619	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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BC51_52_53PAS_SER

45 V/60 V/80 V, 1 A PNP medium power transistors

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NXP Semiconductors

45 V/60 V/80 V, 1 A PNP medium power transistors

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